

# CGH27030S 30 W, DC - 6.0 GHz, 28 V, GaN HEMT

#### Description

The CGH27030S is an unmatched, gallium nitride (GaN) high electron mobility transistor (HEMT) designed specifically for high efficiency, high gain and wide bandwidth capabilities, which makes the CGH27030S ideal for LTE, 4G Telecom and BWA amplifier applications. The CGH27030S operates from a 28 volt rail. The transistor is available in a 3mm x 4mm, surface mount, dual-flat-no-lead (DFN) package.



Package Type: 3x4 DFN PN: CGH27030S

## Typical Performance 1.8-2.7 GHz (T<sub>c</sub> = 25°C), 28 V

| Parameter                                       | <b>1.8 GHz</b> <sup>1</sup> | <b>2.0 GHz</b> <sup>1</sup> | <b>2.2 GHz</b> <sup>1</sup> | <b>2.3 GHz</b> <sup>2</sup> | <b>2.5 GHz</b> <sup>2</sup> | <b>2.7 GHz</b> <sup>2</sup> | Units |
|---|-----------------------------|-----------------------------|-----------------------------|-----------------------------|-----------------------------|-----------------------------|-------|
| Small Signal Gain                               | 20.0                        | 20.4                        | 19.5                        | 21.1                        | 20.6                        | 20.0                        | dB    |
| Adjacent Channel Power @ P <sub>AVE</sub> = 5 W | -39.5                       | -42.1                       | -39.1                       | -32.0                       | -36.4                       | -33.6                       | dBc   |
| Drain Efficiency @ P <sub>AVE</sub> = 5 W       | 31.8                        | 32.8                        | 33.8                        | 37.8                        | 36.2                        | 35.0                        | %     |
| Input Return Loss                               | -4.2                        | -6.4                        | -7.7                        | -7.3                        | -7.9                        | -7.2                        | dB    |

Notes:

<sup>1</sup> Measured in the CGH27030S-AMP1 amplifier circuit, under 7.5 dB PAR single carrier WCDMA signal test model 1 with 64 DPCH

<sup>2</sup> Measured in the CGH27030S-AMP2 amplifier circuit, under 7.5 dB PAR single carrier WCDMA signal test model 1 with 64 DPCH

#### Features for 28 V in CGH27030S-AMP1

- 1.8 2.2 GHz Operation
- 30 W Typical Output Power
- 18 dB Gain at 5 W P<sub>AVE</sub>
- -39 dBc ACLR at 5 W PAVE
- 33% efficiency at 5 W P<sub>AVE</sub>
- High degree of APD and DPD correction can be applied

#### Features for 28 V in CGH27030S-AMP2

- 2.3 2.7 GHz Operation
- 30 W Typical Output Power
- 18.5 dB Gain at 5 W PAVE
- -39 dBc ACLR at 5 W PAVE
- 36% efficiency at 5 W PAVE
- High degree of APD and DPD correction can be applied



Large Signal Models Available for ADS and MWO

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#### Absolute Maximum Ratings (not simultaneous) at 25°C Case Temperature

| Parameter   | Symbol            | Rating    | Units | Conditions |
|---|-------------------|-----------|-------|------------|
| Drain-Source Voltage                                | V <sub>DSS</sub>  | 120       | V     | 25°C       |
| Gate-to-Source Voltage                              | V <sub>GS</sub>   | -10, +2   | V     | 25 C       |
| Storage Temperature                                 | T <sub>STG</sub>  | -65, +150 | °C    |            |
| Operating Junction Temperature                      | TJ                | 225       |       |            |
| Maximum Forward Gate Current                        | I <sub>GMAX</sub> | 7.2       | mA    | - 25°C     |
| Maximum Drain Current <sup>1</sup>                  | I <sub>DMAX</sub> | 3.0       | А     | - 25°C     |
| Soldering Temperature <sup>2</sup>                  | Ts                | 245       | °C    |            |
| Case Operating Temperature <sup>3</sup>             | T <sub>c</sub>    | -40, +150 |       |            |
| Thermal Resistance, Junction to Case <sup>4,5</sup> | R <sub>θJC</sub>  | 3.65      | °C/W  | 85°C       |

Notes:

<sup>1</sup> Current limit for long term, reliable operation

<sup>2</sup> Refer to the Application Note on soldering

 $^3$  Tc = Case temperature for the device. It refers to the temperature at the ground tab underneath the package. The PCB will add additional thermal resistance

 $^4$  Simulated for the CGH27030S at  $\rm P_{\rm DISS}$  = 21.6 W

 $^5$  The R<sub>TH</sub> for the demonstration amplifier, CGH27030S-AMP1, with 33 x 0.011 via holes designed on a 20 mil thick Rogers 4350 PCB, is 3.51°C. The total R<sub>TH</sub> from the heat sink to the junction is 3.62°C + 3.51°C = 7.13 °C/W

## Electrical Characteristics (T<sub>c</sub> = 25°C)

| Characteristics   | Symbol               | Min. | Тур. | Max. | Units           | Conditions  |
|---|----------------------|------|------|------|-----------------|---|
| DC Characteristics <sup>1</sup>   | ,<br>,               |      | ·    | ·    | ·               | ·   |
| Gate Threshold Voltage  | V <sub>GS(th)</sub>  | -3.8 | -3.0 | -2.3 |                 | $V_{DS} = 10 \text{ V}, I_{D} = 7.2 \text{ mA}$   |
| Gate Quiescent Voltage  | V <sub>GS(Q)</sub>   | _    | -2.7 | -    | VDC             | V <sub>DS</sub> = 28 V, I <sub>D</sub> = 0.20 mA  |
| Saturated Drain Current   | I <sub>DS</sub>      | 5.0  | 7.0  | -    | A               | $V_{DS} = 6.0 \text{ V}, V_{GS} = 2.0 \text{ V}$  |
| Drain-Source Breakdown Voltage  | V <sub>(BR)DSS</sub> | 84   | _    | -    | V <sub>DC</sub> | $V_{GS} = -8 V$ , $I_{D} = 7.2 mA$  |
| RF Characteristics <sup>3</sup> (T <sub>c</sub> = 25°C, F₀ = 2.65 GHz unless otherwise noted) |                      |      |      |      |                 |   |
| Gain  | G                    | _    | 19.1 | -    | dB              | $V_{DD} = 28 \text{ V}, I_{DQ} = 0.20 \text{ A}, P_{IN} = 10 \text{ dBm}$                                   |
| Output Power  | Pout                 | _    | 44.9 | -    | dBm             |   |
| Drain Efficiency <sup>3</sup>   | η                    | _    | 72   | -    | %               | $V_{DD} = 28 \text{ V}, I_{DQ} = 0.20 \text{ A}, P_{IN} = 30 \text{ dBm}$                                   |
| Output Mismatch Stress  | VSWR                 | _    | _    | 10:1 | Ψ               | No damage at all phase angles,<br>$V_{DD} = 28 \text{ V}, I_{DQ} = 0.20 \text{ A}, P_{IN} = 30 \text{ dBm}$ |
| Dynamic Characteristics   |                      |      |      |      |                 |   |
| Input Capacitance <sup>4</sup>  | C <sub>GS</sub>      | _    | 8.6  | -    |                 |   |
| Output Capacitance <sup>4</sup>   | C <sub>DS</sub>      | _    | 2.0  | _    | pF              | $V_{DS} = 28 V$ , $V_{GS} = -8 V$ , $f = 1 MHz$   |
| Feedback Capacitance  | C <sub>GD</sub>      | _    | 0.4  | _    | 1               |   |

Notes:

<sup>1</sup> Measured on wafer prior to packaging

<sup>2</sup> Measured in the production test fixture. This fixture is designed for high volume test at 2.65 GHz

<sup>3</sup> Un-modulated Pulsed Signal, 100µs, 10% duty cycle

<sup>4</sup> Includes package and internal matching components

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## Typical Performance in CGH27030S-AMP1

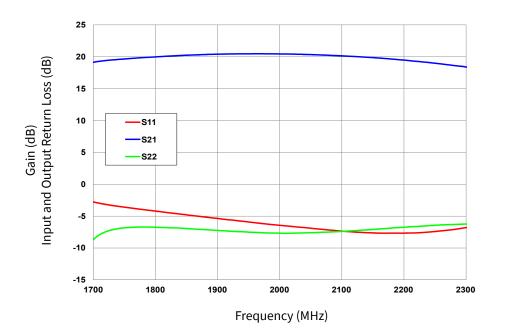
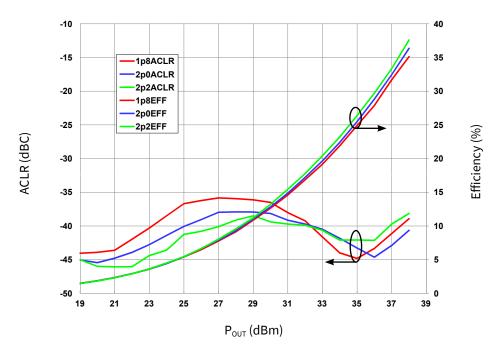
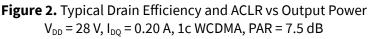


Figure 1. Small Signal Gain and Return Losses vs Frequency  $V_{\text{DD}}$  = 28 V,  $I_{\text{DQ}}$  = 0.20 A





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## Typical Performance in CGH27030S-AMP1

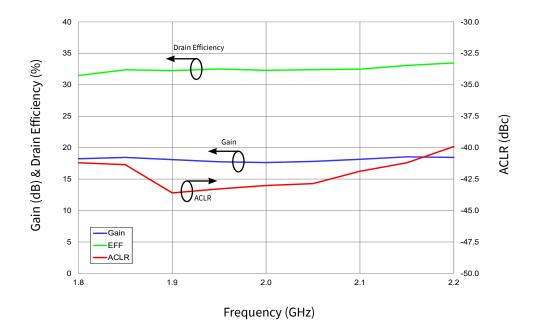
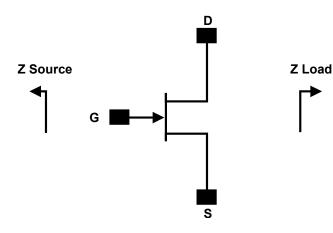


Figure 3. Typical Gain, Drain Efficiency and ACLR vs Frequency  $V_{DD} = 28 \text{ V}$ ,  $I_{DQ} = 0.20 \text{ A}$ ,  $P_{AVE} = 5 \text{ W}$ , 1c WCDMA, PAR = 7.5 dB

#### Source and Load Impedances for Application Circuit CGH27030S-AMP1



| Frequency | Z Source   | Z Load      |
|-----------|------------|-------------|
| 1800      | 3.5 – j1.6 | 11 + j0.2   |
| 2000      | 3.6 – j0.6 | 10.5 – j1.8 |
| 2200      | 3.3 – j0.1 | 11 + j3.3   |

Notes:

 $^1$  V\_{\text{DD}} = 28 V, I $_{\text{DO}}$  = 0.20 A in the DFN package

<sup>2</sup> Impedances are extracted from the CGH27030S-AMP1 application circuit and are not source and load pull data derived from the transistor

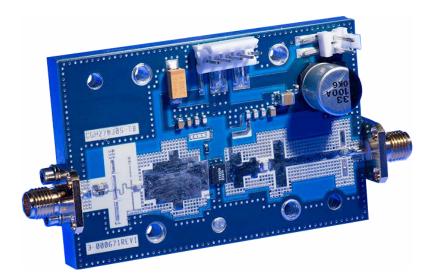
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## CGH27030S-AMP1 Application Circuit Bill of Materials

| Designator      | Description   | Qty |
|-----------------|---|-----|
| R1              | RES, 1/16 W, 0603, 1%, 100 OHMS                         | 1   |
| R2              | RES, 1/16 W, 0603, 1%, 5.1 OHMS                         | 1   |
| C1              | CAP, 6.8pF, ±0.25pF, 0603, ATC                          | 1   |
| C2              | CAP, 2.4pF, ±0.01pF, 0603, ATC                          | 1   |
| C3, C8, C9, C10 | CAP, 10.0pF, ±0.5pF, 0603, ATC                          | 3   |
| C12             | CAP, 100.0pF, 5%, 0603, ATC                             | 1   |
| C5              | CAP, 470pF, 5%, 100 V, 0603                             | 1   |
| C6, C13         | CAP, 33000pF, 0805, 10%, 100 V, X7R                     | 2   |
| C14             | CAP, 1.0μF, 100 V, 10%, X7R, 1210                       | 1   |
| C7              | CAP, 10µF, 16 V, TANTALUM                               | 1   |
| C15             | CAP, 33µF, 20%, G CASE                                  | 1   |
| J1, J2          | CONN, SMA, PANEL MOUNT JACK, FLANGE, 4-HOLE, BLUNT POST | 2   |
| Q1              | CGH27030S, QFN  | 1   |

## CGH27030S-AMP1 Application Circuit, 28 V, 1.8 - 2.2 GHz

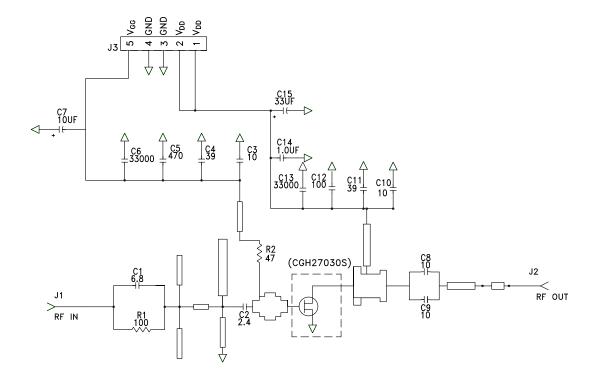


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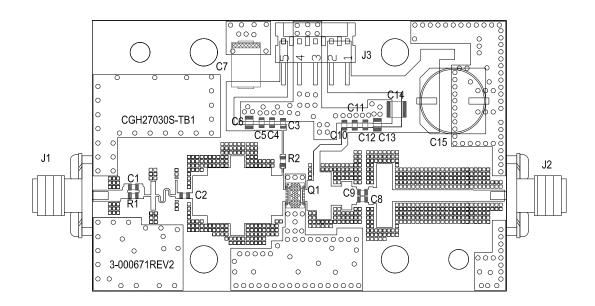
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### CGH27030S-AMP1 Application Circuit Schematic, 28 V, 1.8 - 2.2 GHz



### CGH27030S-AMP1 Application Circuit, 28 V, 1.8 - 2.2 GHz



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## CGH27030S



## Typical Performance in Application Circuit CGH27030S-AMP2

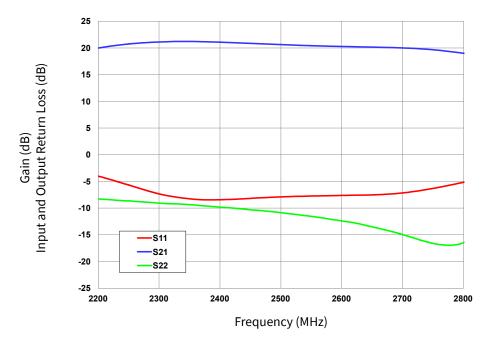
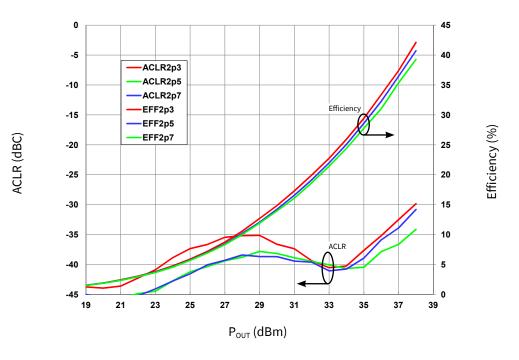
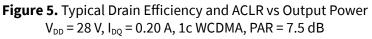


Figure 4. Small Signal Gain and Return Losses vs Frequency  $V_{DD}$  = 28 V,  $I_{DQ}$  = 0.20 A





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# CGH27030S



## Typical Performance in Application Circuit CGH27030S-AMP2

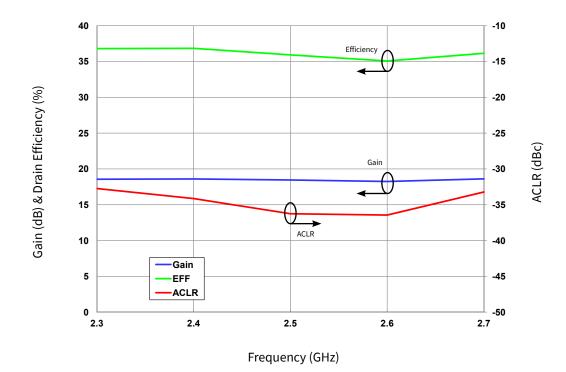


Figure 6. Typical Gain, Drain Efficiency and ACLR vs Frequency  $V_{DD} = 28 \text{ V}, I_{DQ} = 0.20 \text{ A}, P_{AVE} = 5 \text{ W}, 1c \text{ WCDMA}, PAR = 7.5 \text{ dB}$ 

## **Electrostatic Discharge (ESD) Classifications**

| Parameter           | Symbol | Class | Classification Level           | Test Methodology    |
|---------------------|--------|-------|--------------------------------|---------------------|
| Human Body Model    | НВМ    | 1B    | ANSI/ESDA/JEDEC JS-001 Table 3 | JEDEC JESD22 A114-D |
| Charge Device Model | CDM    | С3    | ANSI/ESDA/JEDEC JS-002 Table 3 | JEDEC JESD22 C101-C |

### **Moisture Sensitivity Level (MSL) Classification**

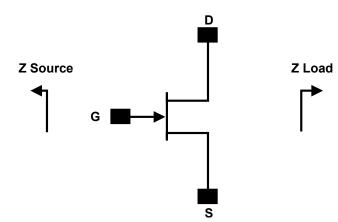
| Parameter                  | Symbol | Level         | Test Methodology   |
|----------------------------|--------|---------------|--------------------|
| Moisture Sensitivity Level | MSL    | 3 (168 hours) | IPC/JEDEC J-STD-20 |

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#### Source and Load Impedances for Application Circuit CGH27030S-AMP2



| Frequency | Z Source   | Z Lead     |
|-----------|------------|------------|
| 2300      | 1.7 – j0.5 | 7.7 + j7.7 |
| 2500      | 2.2 – j0.2 | 8.0 + j6.8 |
| 2700      | 1.5 – j0.1 | 6.6 + j6.3 |

Notes:

 $^{1}$  V<sub>DD</sub> = 28 V, I<sub>DO</sub> = 0.20 A in the DFN package

<sup>2</sup> Impedances are extracted from the CGH27030S-AMP2 application circuit and are not source and load pull data derived from the transistor

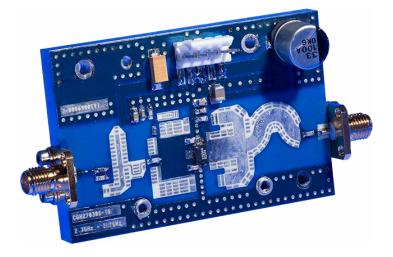
#### CGH27030S-AMP1 Application Circuit Bill of Materials

| Designator | Description   | Qty |
|------------|---|-----|
| R1, R2     | RES, 22.6, OHM, +/-1%, 1/16W, 0603                      | 2   |
| C1         | CAP, 3.3pF, ±0.1pF, 0603, ATC                           | 1   |
| C2         | CAP, 0.9pF, ±0.1pF, 0603, ATC                           | 1   |
| C3         | CAP, 1.2pF, ±0.1pF, 0603, ATC                           | 1   |
| C4         | CAP, 1.5pF, ±0.1pF, 0603, ATC                           | 1   |
| C5, C9     | CAP, 8.2pF, ±0.25pF, 0603, ATC                          | 2   |
| C6, C10    | CAP, 470pF, 5%, 100 V, 0603, X                          | 2   |
| C7, C11    | CAP, 33000pF, 0805, 100 V, X7R                          | 2   |
| C12        | CAP, 1.0μF, 100 V, 10%, X7R, 1210                       | 1   |
| C8         | CAP, 10μF 16 V TANTALUM                                 | 1   |
| C14        | CAP, 27pF, ±5%, 0603, ATC                               | 1   |
| C13        | CAP, 33µF, 20%, G CASE                                  | 1   |
| J1, J2     | CONN, SMA, PANEL MOUNT JACK, FLANGE, 4-HOLE, BLUNT POST | 1   |
| Q1         | CGH27030S, QFN  | 2   |

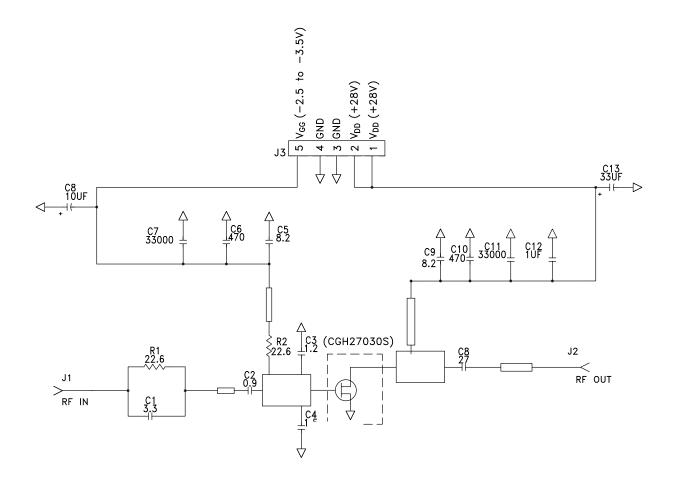
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#### CGH27030S-AMP2 Application Circuit, 28 V, 2.3 - 2.7 GHz



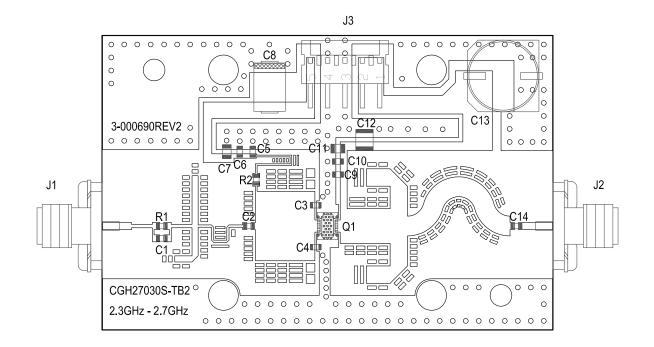
# CGH27030S-AMP2 Application Circuit Schematic, 28 V, 2.3 - 2.7 GHz



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## CGH27030S-AMP2 Application Circuit, 28 V, 2.3 - 2.7 GHz



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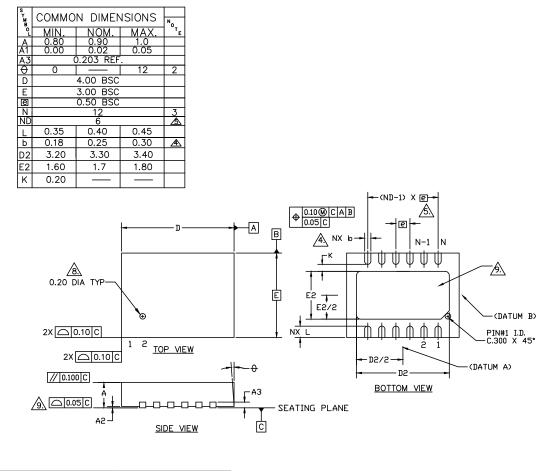
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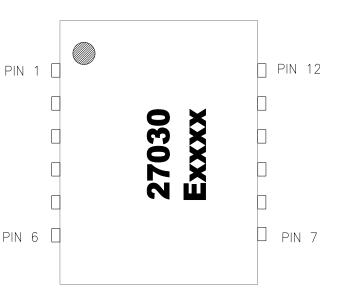
# CGH27030S



#### Product Dimensions CGH27030S (Package 3 x 4 DFN)



| Pin | Input/Output |
|-----|--------------|
| 1   | GND          |
| 2   | RF IN        |
| 3   | RF IN        |
| 4   | RF IN        |
| 5   | RF IN        |
| 6   | GND          |
| 7   | GND          |
| 8   | RF OUT       |
| 9   | RF OUT       |
| 10  | RF OUT       |
| 11  | RF OUT       |
| 12  | GND          |

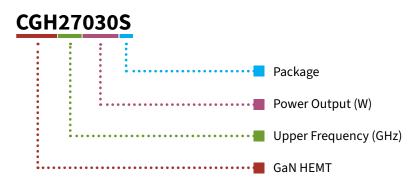


Note: Leadframe finish for 3x4 DFN package is Nickel/Palladium/Gold. Gold is the outer layer.

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#### **Part Number System**



#### Table 1.

| Parameter                    | Value         | Units |
|------------------------------|---------------|-------|
| Upper Frequency <sup>1</sup> | 2.7           | GHz   |
| Power Output                 | 30            | W     |
| Package                      | Surface Mount | -     |

Note:

<sup>1</sup> Alpha characters used in frequency code indicate a value greater than 9.9 GHz. See Table 2 for value.

#### Table 2.

| Character Code | Code Value                     |
|----------------|--------------------------------|
| A              | 0                              |
| В              | 1                              |
| С              | 2                              |
| D              | 3                              |
| E              | 4                              |
| F              | 5                              |
| G              | 6                              |
| н              | 7                              |
| J              | 8                              |
| К              | 9                              |
| Examples       | 1A = 10.0 GHz<br>2H = 27.0 GHz |

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# **Product Ordering Information**

| Order Number   | Description                        | Unit of Measure | Image  |
|----------------|------------------------------------|-----------------|--------|
| CGH27030S      | GaN HEMT                           | Each            | 228307 |
| CGH27030S-AMP1 | Test board without GaN HEMT        | Each            |        |
| CGH27030S-AMP2 | Test board with GaN HEMT installed | Each            |        |



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